



UNIVERSITY OF CALCUTTA

Applications are invited for ONE Junior Research Fellow (@Rs. 25000/= pm + applicable HRA as per Gol norms) for the project “**High Responsivity GeSn Short Wave Infrared Phototransistors**” under Indo-Taiwan Joint Research Programme in Science and Technology sponsored by Global Innovation & Technology Alliance (GITA) on behalf of DST, Govt. of India under Dr. Bratati Mukhopadhyay, Assistant Professor, Radio Physics and Electronics (RPE), University of Calcutta and Dr. Rikmantra Basu, NIT, Delhi.

The candidates must have post graduate degree in Physics or Electronic Science with NET qualification or B.Tech in Radio Physics and Electronics or equivalent with GATE qualification or M.Tech in Radio Physics and Electronics or equivalent.

The termination date of the project is January 3, 2019.

Application in plain paper attaching CV, all contact and e-mail addresses, and giving attested copies of all relevant documents and reprints, if any, must reach Dr. Bratati Mukhopadhyay, Principal Investigator, DST project **High Responsivity GeSn Short Wave Infrared Phototransistors**, Department of Radio Physics and Electronics, 92 APC Road, Kolkata 700009, on or before 28.03.2016 .

The date of interview will be notified to the short listed candidates by e-mail.